

#### **QUADRUPLE 3-STATE BUFFERS OE LOW**

## **Description**

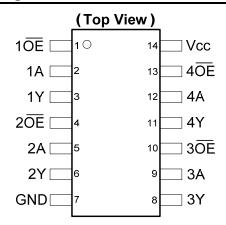
The 74AHCT125 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a high logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 4.5V to 5.5V.

#### **Features**

Notes:

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V<sub>CC</sub> = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Pin Assignments**



SO-14 / TSSOP-14

## **Applications**

- General Purpose Logic
- Wide array of products such as:
  - PCs, Networking, Notebooks, Netbooks
  - Computer Peripherals, Hard Drives, CD/DVD ROM
  - TV, DVD, DVR, Set Top Box

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet



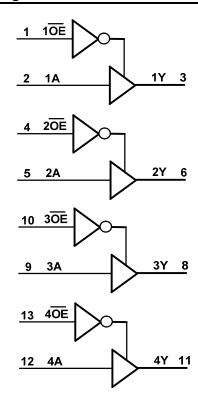
## **Pin Descriptions**

Pin Number	Pin Name	Function
1	10E	Data Enable Input (active low)
2	1A	Data Input
3	1Y	Data Output
4	2 <del>OE</del>	Data Enable Input (active low)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3 <del>OE</del>	Data Enable Input (active low)
11	4Y	Data Output
12	4A	Data Input
13	4OE	Data Enable Input (active low)
14	V <sub>CC</sub>	upply Voltage

# **Function Table**

Inp	Output	
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	X	Z

# **Logic Diagram**



# Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
lok	Output Clamp Current V <sub>O</sub> < 0V	-20	mA
lok	Output Clamp Current Vo > Vcc	20	mA
Io	Continuous Output Current OV < V <sub>O</sub> < V <sub>CC</sub>	+/- 25	mA
Icc	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



## Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	Vcc	V
Δt/ΔV	Input Transition Rise or Fall Rate		20	ns/V
T <sub>A</sub>	Operating Free-Air Temperature	-40	+125	°C

Note:

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cumbal	Parameter	Test Conditions	V	T <sub>A</sub> = -40°	C to +85°C	T <sub>A</sub> = -40°C	to +125°C	Unit
Symbol	Parameter	rest Conditions	V <sub>CC</sub>	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		V
VIL	Low-Level Input Voltage		4.5V to 5.5V		0.8		0.8	V
\ /	High-Level	I <sub>OH</sub> = -50μA	4.5V	4.4		4.4		V
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -8mA	4.5V	3.80		3.70		V
V	Low-Level Output	I <sub>OL</sub> = 50μA	4.5V		0.1		0.1	V
V <sub>OL</sub>	Voltage	I <sub>OL</sub> = 8mA	4.5V		0.44		0.55	\ \ \
l <sub>OZ</sub>	Z State Leakage Current	V <sub>O</sub> = 0 to 5.5V	5.5V		±2.5		±10	μA
II	Input Current	$V_I$ = GND to 5.5V	3.6V		±1		±2	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V	•	20		40	μΑ
ΔI <sub>CC</sub>	Additional Supply Current	One input at V <sub>CC</sub> -2.1V Other pins at V <sub>CC</sub> or GND	5.5V		1.35		5	mA

# **Operating Characteristics**

	Parameter		V <sub>CC</sub> = 5.5V	Unit
		Conditions	Тур	Oiiit
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	f = 1MHz	14.8	pF
C <sub>i</sub>	Input Capacitance	$V_i = V_{CC} - or$ GND	4.0	pF

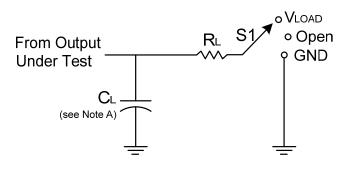
# **Switching Characteristics**

Symbol	Parameter	Test Conditions	T <sub>A</sub> = +25°C		-40°C to +85°C		-40°C to +125°C		Unit	
Syllibol	Faranietei	rest Conditions	Min	Тур.	Max	Min	Max	Min	Max	Ullit
	Drangation Dalay A to V	Figure 1 C <sub>L</sub> = 15pF	0.5	3.0	5.5	0.5	6.5	0.5	7.0	20
t <sub>PD</sub>	Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 50pF	0.5	4.3	7.5	0.5	8.5	0.5	9.5	ns
	Enable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF	0.5	6.7	10.7	0.5	11.0	0.5	11.5	20
t <sub>EN</sub>	Eliable fillie OEN to fn	Figure 1 C <sub>L</sub> = 50pF	0.5	9.8	10.9	0.5	12.1	0.5	12.5	ns
	Disable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF	0.5	4.8	6.8	0.5	8.0	0.5	8.5	20
t <sub>DIS</sub>	DISABLE TITLE OEN TO TH	Figure 1 C <sub>L</sub> = 50pF	0.5	6.5	8.9	0.5	10.0	0.5	11.5	ns

<sup>5.</sup> Unused inputs should be held at  $V_{\text{CC}}$  or Ground.

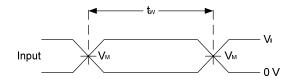


## **Parameter Measurement Information**

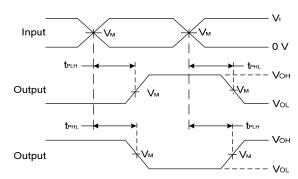


TEST	<b>S1</b>
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	Vload
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

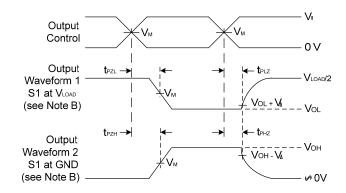
V	Inputs		V <sub>M</sub> V <sub>M</sub>		V		Б	<b>V</b> A
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	Inputs	Outputs	VLOAD	CL	KL	<b>V</b> Δ
4.5V to 5.5V	3V	≤3ns	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub>	15pF, 50pF	1K	0.3V



#### **Voltage Waveform Pulse Duration**



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.

C. Inputs are measured separately one transition per measurement.

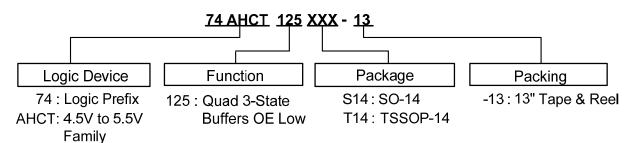
D.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .

E. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>EN0</sub>.

F.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{PD}}.$ 



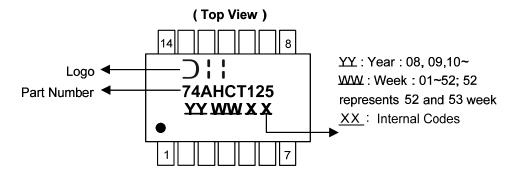
## **Ordering Information**



Part Number	Backage Code	Dookoging	7" Tape	and Reel
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHCT125S14-13	S14	SO-14	2500/Tape & Reel	-13
74AHCT125T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

## **Marking Information**

#### (1) SO-14, TSSOP-14



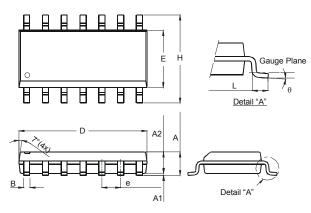
Part Number	Package
74AHCT125S14	SO-14
74AHCT125T14	TSSOP-14



## Package Outline Dimensions (All dimensions in mm.)

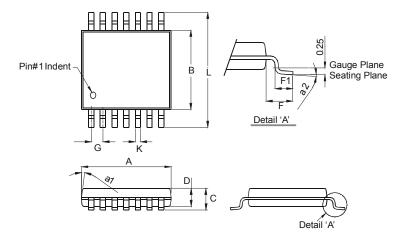
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Din	nensions	in mm				

## Package Type: TSSOP-14



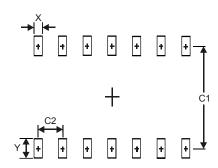
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
C	_	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



## **Suggested Pad Layout**

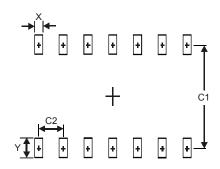
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### Package Type: SO-14



Dimensions	Value (in mm)	
Х	0.60	
Υ	1.50	
C1	5.4	
C2	1.27	

#### Package Type: TSSOP-14



Dimensions	Value (in mm)	
Х	0.45	
Υ	1.45	
C1	5.9	
C2	0.65	



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